
DISCRETE POWER DIODES and THYRISTORS
DATA BOOK

PHASE CONTROL THYRISTORS

Stud Version

Features

- Hermetic glass-metal seal
- $dv/dt = 1000V/\mu s$ option
- International standard case TO-209AB (TO-93)
- Threaded studs UNF 3/4 - 16UNF2A

180A

Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers

Major Ratings and Characteristics

Parameters	181RKI	Units
$I_{T(AV)}$	180	A
@ T_C	80	$^{\circ}C$
$I_{T(RMS)}$	285	A
I_{TSM} @ 50Hz	3800	A
@ 60Hz	4000	A
I^2t @ 50Hz	72	KA^2s
@ 60Hz	66	KA^2s
V_{DRM}/V_{RRM}	400 to 1000	V
t_q typical	100	μs
T_J	- 40 to 125	$^{\circ}C$



case style
TO-209AB (TO-93)

ELECTRICAL SPECIFICATIONS**Voltage Ratings**

Type number	Voltage Code	$V_{\text{DRM}}/V_{\text{RRM}}$, max. repetitive peak and off-state voltage V	V_{RSM} , maximum non-repetitive peak voltage V	$I_{\text{DRM}}/I_{\text{RRM}}$ max. @ $T_J = T_J$ max. mA
181RKI	40	400	500	30
	80	800	900	
	100	1000	1100	

On-state Conduction

Parameter	181RKI	Units	Conditions
$I_{\text{T(AV)}}$ Max. average on-state current @ Case temperature	180	A	180° conduction, half sine wave
	80	°C	
$I_{\text{T(RMS)}}$ Max. RMS on-state current	285	A	DC @ 79°C case temperature
I_{TSM} Max. peak, one-cycle non-repetitive surge current	3800		t = 10ms No voltage
	4000		t = 8.3ms reapplied
	3500		t = 10ms 100% V_{RRM}
	3660		t = 8.3ms reapplied
I^2t Maximum I^2t for fusing	72	KA^2s	t = 10ms No voltage
	66		t = 8.3ms reapplied
	61		t = 10ms 100% V_{RRM}
	56		t = 8.3ms reapplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	720	$\text{KA}^2\sqrt{\text{s}}$	t = 0.1 to 10ms, no voltage reapplied
$V_{\text{T(TO)1}}$ Low level value of threshold voltage	0.83	V	$(16.7\% \times \pi \times I_{\text{T(AV)}} < I < \pi \times I_{\text{T(AV)}}), T_J = T_J$ max.
$V_{\text{T(TO)2}}$ High level value of threshold voltage	0.89		$(I > \pi \times I_{\text{T(AV)}}), T_J = T_J$ max.
r_{t1} Low level value of on-state slope resistance	0.92	$\text{m}\Omega$	$(16.7\% \times \pi \times I_{\text{T(AV)}} < I < \pi \times I_{\text{T(AV)}}), T_J = T_J$ max.
r_{t2} High level value of on-state slope resistance	0.81		$(I > \pi \times I_{\text{T(AV)}}), T_J = T_J$ max.
V_{TM} Max. on-state voltage	1.35	V	$I_{\text{pk}} = 570\text{A}, T_J = T_J$ max, $t_p = 10\text{ms}$ sine pulse
I_{H} Maximum holding current	600	mA	$T_J = 25^\circ\text{C}$, anode supply 12V resistive load
I_{L} Typical latching current	1000		

Switching

Parameter	181RKI	Units	Conditions
di/dt Max. non-repetitive rate of rise of turned-on current	300	A/ μs	Gate drive 20V, 20Ω , $t_r \leq 1\mu\text{s}$ $T_J = T_J$ max, anode voltage $\leq 80\% V_{\text{DRM}}$
t_d Typical delay time	1.0	μs	Gate current 1A, $di_g/dt = 1\text{A}/\mu\text{s}$ $V_d = 0.67\% V_{\text{DRM}}, T_J = 25^\circ\text{C}$
t_q Typical turn-off time	100		$I_{\text{TM}} = 50\text{A}, T_J = T_J$ max, $di/dt = 10\text{A}/\mu\text{s}$, $V_R = 100\text{V}$ $dv/dt = 20\text{V}/\mu\text{s}$

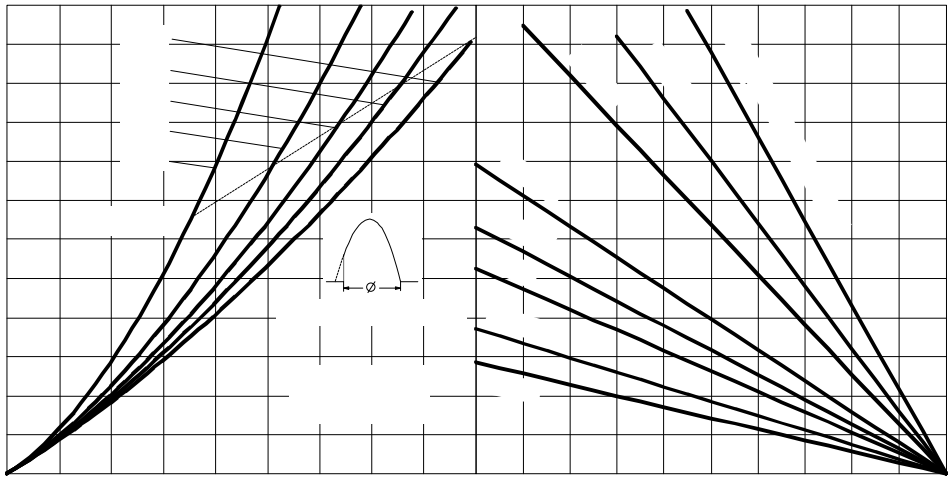


Fig. 3 - On-state Power Loss Characteristics

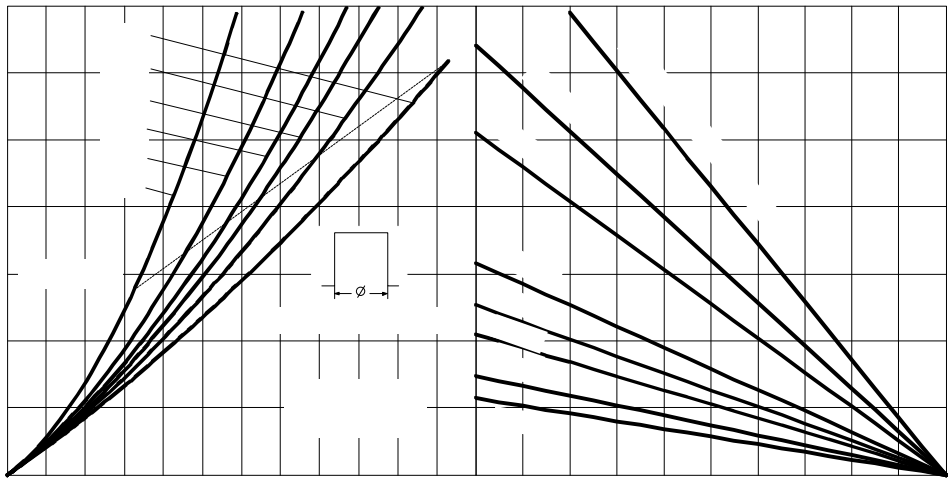


Fig. 4 - On-state Power Loss Characteristics

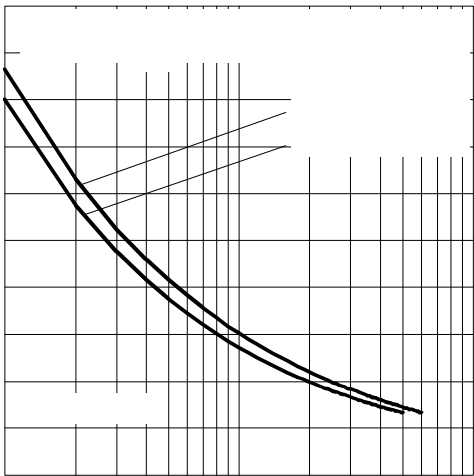


Fig. 5 - Maximum Non-Repetitive Surge Current

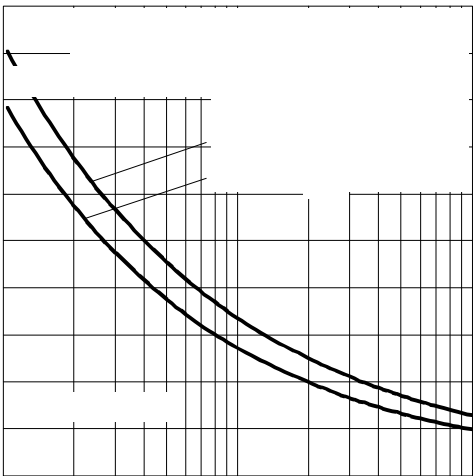


Fig. 6 - Maximum Non-Repetitive Surge Current

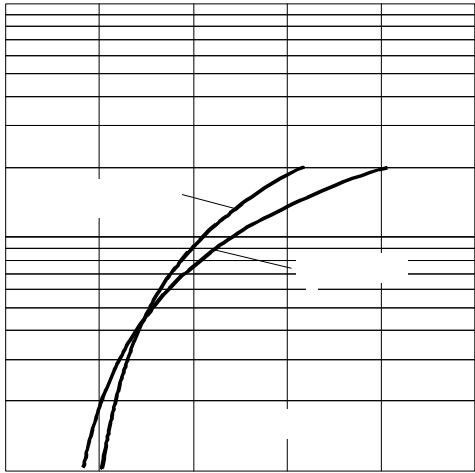


Fig. 7 - On-state Voltage Drop Characteristics

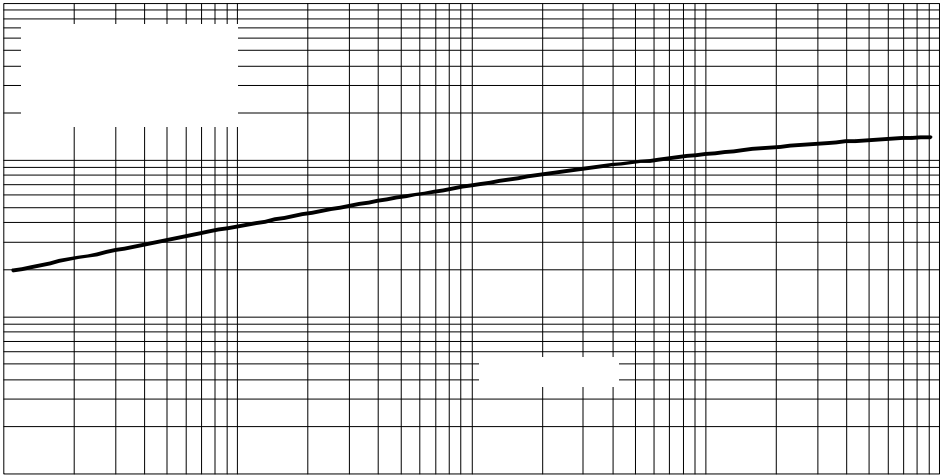


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic

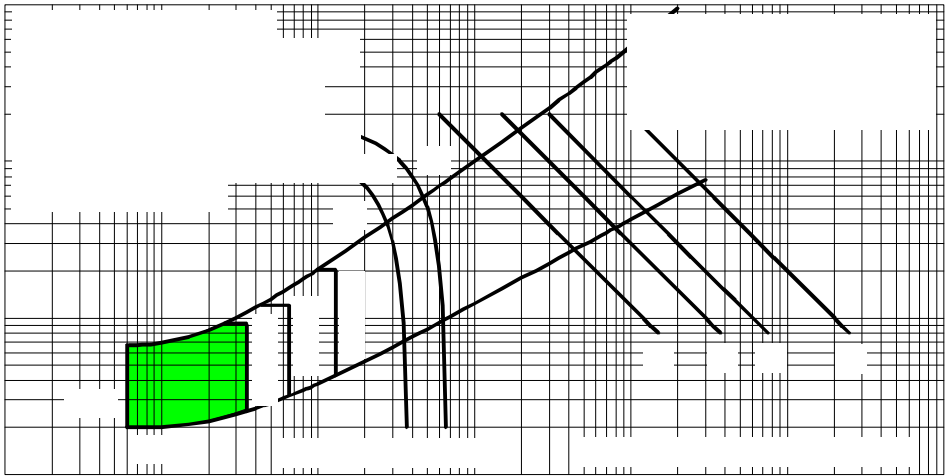


Fig. 9 - Gate Characteristics

Blocking

Parameter	181RKI	Units	Conditions
dv/dt Maximum critical rate of rise of off-state voltage	500	V/ μ s	$T_J = T_J$ max. linear to 80% rated V_{DRM}
I_{RRM} I_{DRM} Max. peak reverse and off-state leakage current	30	mA	$T_J = T_J$ max, rated V_{DRM}/V_{RRM} applied

Triggering

Parameter	181RKI	Units	Conditions
P_{GM} Maximum peak gate power	10	W	$T_J = T_J$ max, $t_p \leq 5ms$
$P_{G(AV)}$ Maximum average gate power	2.0		$T_J = T_J$ max, $f = 50Hz$, $d\% = 50$
I_{GM} Max. peak positive gate current	3.0	A	$T_J = T_J$ max, $t_p \leq 5ms$
$+V_{GM}$ Maximum peak positive gate voltage	20	V	$T_J = T_J$ max., $t_p \leq 5ms$
$-V_{GM}$ Maximum peak negative gate voltage	5.0		
I_{GT} DC gate current required to trigger	TYP.	MAX.	$T_J = -40^\circ C$ $T_J = 25^\circ C$ $T_J = 125^\circ C$ Max. required gate trigger/ current/ voltage are the lowest value which will trigger all units 12V anode-to-cathode applied
	130	-	
	65	150	
	35	-	
V_{GT} DC gate voltage required to trigger	2.0	-	$T_J = -40^\circ C$ $T_J = 25^\circ C$ $T_J = 125^\circ C$
	1.2	2.5	
	0.9	-	
I_{GD} DC gate current not to trigger	10	mA	$T_J = T_J$ max. Max. gate current/ voltage not to trigger is the max. value which will not trigger any unit with rated V_{DRM} anode-to-cathode applied
V_{GD} DC gate voltage not to trigger	0.25	V	

Thermal and Mechanical Specification

Parameter	181RKI	Units	Conditions
T_J Max. operating temperature range	-40 to 125	$^\circ C$	
T_{stg} Max. storage temperature range	-40 to 150		
R_{thJC} Max. thermal resistance, junction to case	0.15	K/W	DC operation
R_{thCS} Max. thermal resistance, case to heatsink	0.04		Mounting surface, smooth, flat and greased
T Mounting torque, $\pm 10\%$	31	Nm (lbf-in)	Non lubricated threads
	(275)		
	24.5 (210)		Lubricated threads
wt Approximate weight	280	g	
Case style	TO - 209AB (TO-93)		See Outline Table

181RKI Series

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.050	0.032	K/W	$T_J = T_J \text{ max.}$
120°	0.063	0.059		
90°	0.080	0.082		
60°	0.118	0.124		
30°	0.225	0.228		

Ordering Information Table

Device Code

18

1

RKI

100

1

2

3

4

5

6

1

-

$I_{T(AV)}$ rated average output current (rounded/10)

2

-

0 = Eyelet terminals (Gate and Auxiliary Cathode Leads)
1 = Fast - on terminals (Gate and Auxiliary Cathode Leads)
2 = Flag terminals (For Cathode and Gate Terminals)

3

-

Thyristor

4

-

Voltage code: Code x 10 = V_{RRM} (See Voltage Rating Table)

5

-

None = Stud base UNF 3/4 - 16UNF threads

6

-

Critical dv/dt: None = 500V/ μ sec
S90 = 1000V/ μ sec

Outline Table

GLASS-METAL SEAL

FLAG TERMINAL

Technical drawing of the 181RKI Series thyristor showing front, side, and top views with dimensions in millimeters (mm) and inches (in).

Front View Dimensions:

- Total height: 70 (2.75) MAX.
- Height to top of flag terminal: 28.5 (1.12) MAX.
- Height to top of main body: 16 (0.63) MAX.
- Height to base of main body: 21 (0.83) MAX.
- Base diameter: 3/4"-16UNF-2A
- Base width: 3 (0.12)

Side View Dimensions:

- Flag terminal length: 18 (0.71)
- Flag terminal width: 11 (0.43)
- Flag terminal diameter: DIA. 6.5 (0.26)
- Flag terminal thickness: 13 (0.51)
- Flag terminal hole diameter: 1.5 (0.06) DIA.
- Main body diameter: DIA. 28 (1.1) MAX.
- Material: SW 32

Case Style TO-209AB (TO-93) Flag

All dimensions in millimeters (inches)

Outline Table

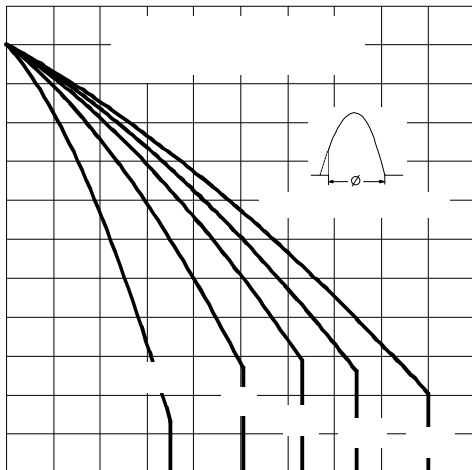
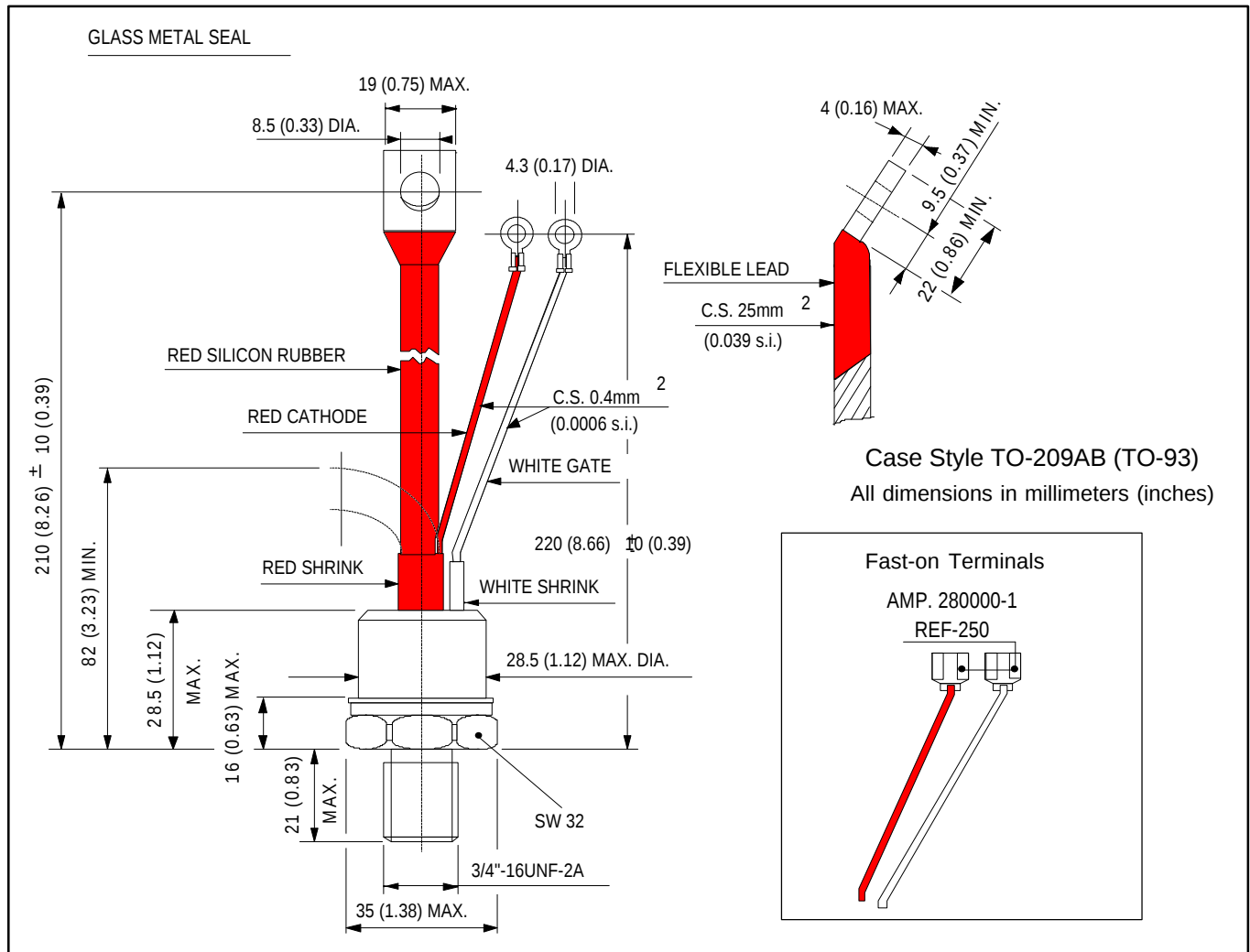


Fig. 1 - Current Ratings Characteristics

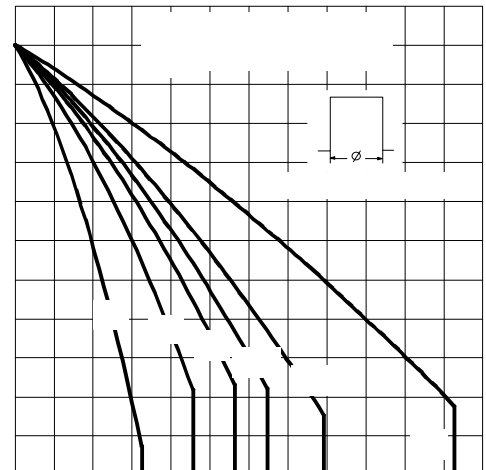


Fig. 2 - Current Ratings Characteristics